

Features

- Integrated analog input Class D audio amplifier driver in a small 16 pin package
- Floating inputs enable easy half bridge implementation
- Programmable bidirectional over-current protection with self-reset function
- Programmable preset deadtime for improved THD performances
- Start and stop click noise reduction
- High noise immunity
- ± 100 V ratings deliver up to 500 W in output power
- Operates up to 800 kHz
- Leadfree, RoHS compliant
- Automotive Qualified^T

Product Summary

V _{OFFSET} (max)		± 100 V
Gate driver	Io+ (typical)	1.0 A
	Io- (typical)	1.2 A
Selectable Deadtime		25/40/65/105 ns
OC protection delay (max)		500 ns
DC offset		<20 mV
PWM frequency		~800 kHz
Error amplifier open loop gain		>60 dB
THD+N* (1kHz, 50W, 4 Ω)		0.01 %
Residual Noise* (AES-17 Filter)		200 μ Vrms

* measured with recommended circuit

Typical Applications

- Automotive mini component stereo systems
- Automotive powered speaker systems
- Automotive audio power amplifiers

Package Options



SOIC-16L Narrow Body

Typical Connection Diagram

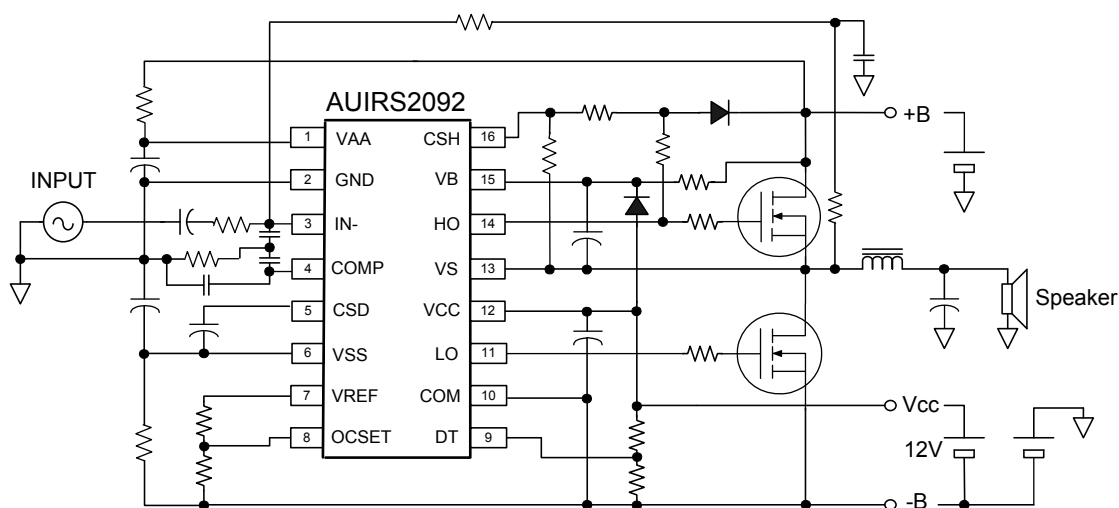


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Description

The AUIRS2092 is a high voltage, high performance Class D audio amplifier driver with PWM modulator and protection. In conjunction with two external MOSFET and a few external components, a complete Class D audio amplifier with protection can be realized.

International Rectifier's proprietary noise isolation technology allows high current gate drive stage and high speed low noise error amplifier reside on a single small silicon die.

Open elements of PWM modulator section allow flexible PWM topology implementation.

The diagram illustrates the internal architecture of the HV0100 HV driver. Key components and their connections include:

- Inputs:** VAA, IN-, GND, COMP, VSS, and CSD are provided on the left.
- Core Processing:** The IN- input is processed by an OTA (Operational Transconductance Amplifier) and a COMP (Comparator). The output of the COMP is $\frac{VAA+VSS}{2}$.
- Level Shifting:** Multiple HV LEVEL SHIFT blocks are used to interface between the internal logic and the high-voltage MOSFET gates.
- Protection:** A PROTECTION CONTROL block monitors the CSD input and provides feedback to the HV LEVEL SHIFT blocks.
- Timing:** A DEAD TIME block generates a dead time signal (DT) from the COMP output, which is used to prevent shoot-through in the MOSFETs.
- Outputs:** The circuit drives the gates of a HIGH SIDE CS (Common Source) MOSFET and a LOW SIDE CS (Common Source) MOSFET. The outputs are labeled CSH, VB, HO, VS, VCC, LO, COM, VREF, OCSET, and DT.
- Floating Inputs:** A dashed box labeled "FLOATING INPUT" encloses the COMP and the first HV LEVEL SHIFT block.
- Floating High Side:** A dashed line labeled "FLOATING HIGH SIDE" connects the output of the first HV LEVEL SHIFT block to the input of the second HV LEVEL SHIFT block.

Refer to IRAUDAMP5 reference design for details.

Qualification Information[†]

Qualification Level		Automotive (per AEC-Q100 ^{††})	
		Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
Moisture Sensitivity Level		SOIC16N	MSL3 ^{†††} 260°C (per IPC/JEDEC J-STD-020)
ESD	Machine Model	Class M2 (+/-150V) (per AEC-Q100-003)	
	Human Body Model	Class H1B (+/-750V) (per AEC-Q100-002)	
	Charged Device Model	Class C3A (+/-750V) (per AEC-Q100-011)	
IC Latch-Up Test		Class II, Level B ^{††††} (per AEC-Q100-004)	
RoHS Compliant		Yes	

† Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>

†† Exceptions to AEC-Q100 requirements are noted in the qualification report.

††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

†††† CSD pin stressed to +/-20mA, CSH pin stressed to +/-40mA, DT and OCSET pins stressed to +/-20mA

Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM lead. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the "Recommended Operating Conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

Symbol	Definition	Min	Max	Units
V_B	High side floating supply voltage	-0.3	220	V
V_S	High side floating supply voltage (Note2)	$V_B - 20$	$V_B + 0.3$	
V_{HO}	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{CSH}	CSH pin input voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{CC}	Low side fixed supply voltage (Note2)	-0.3	20	
V_{LO}	Low side output voltage	-0.3	$V_{CC} + 0.3$	
V_{AA}	Floating input positive supply voltage (Note2)	(See I_{AAZ})	210	
V_{SS}	Floating input negative supply voltage (Note2)	-1 (See I_{SSZ})	GND + 0.3	
V_{GND}	Floating input supply ground voltage	$V_{SS} - 0.3$ (See I_{SSZ})	$V_{AA} + 0.3$ (See I_{AAZ})	
I_{IN-}	Inverting input current (Note1)	---	± 3	mA
V_{CSD}	SD pin input voltage	$V_{SS} - 0.3$	$V_{AA} + 0.3$	V
V_{COMP}	COMP pin input voltage	$V_{SS} - 0.3$	$V_{AA} + 0.3$	
V_{DT}	DT pin input voltage	-0.3	$V_{CC} + 0.3$	
V_{OCSET}	OCSET pin input voltage	-0.3	$V_{CC} + 0.3$	
I_{AAZ}	Floating input positive supply zener clamp current (Note2)	---	20	mA
I_{SSZ}	Floating input negative supply zener clamp current (Note2)	---	20	
I_{CCZ}	Low side supply zener clamp current (Note3)	---	10	
I_{BSZ}	Floating supply zener clamp current (Note3)	---	10	
I_{OREF}	Reference output current	---	5	
dV_S/dt	Allowable V_S voltage slew rate	---	50	V/ns
dV_{SS}/dt	Allowable V_{SS} voltage slew rate (Note3)	---	50	V/ms
P_d	Maximum power dissipation @ $T_A \leq +25^\circ\text{C}$	---	1.0	W
R_{thJA}	Thermal resistance, Junction to ambient	---	115	$^\circ\text{C}/\text{W}$
T_J	Junction Temperature	---	150	$^\circ\text{C}$
T_S	Storage Temperature	-55	150	$^\circ\text{C}$
T_L	Lead temperature (soldering, 10 seconds)	---	300	$^\circ\text{C}$

Note1: $IN-$ contains clamping diode to GND.

Note2: $V_{DD} - IN+$, GND - V_{SS} , $V_{CC} - COM$ and $V_B - V_S$ contain internal shunt zener diodes. Please note that the voltage ratings of these can be limited by the clamping current.

Note3: For the rising and falling edges of step signal of 10 V. $V_{SS} = 15\text{ V}$ to 200 V.

Recommended Operating Conditions

For proper operation, the device should be used within the recommended conditions below. The V_S and COM offset ratings are tested with supplies biased at $V_{AA}-V_{SS}=10\text{ V}$, $V_{CC}=12\text{ V}$ and $V_B-V_S=12\text{ V}$. All voltage parameters are absolute voltages referenced to COM; all currents are defined positive into any lead.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	$V_S + 10$	$V_S + 18$	V
V_S	High side floating supply offset voltage	(Note 1)	200	
I_{AAZ}	Floating input positive supply zener clamp current	1	11	mA
I_{SSZ}	Floating input negative supply zener clamp current	1	11	
V_{SS}	Floating input supply absolute voltage	0	200	V
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Low side fixed supply voltage	10	18	
V_{LO}	Low side output voltage	0	V_{CC}	
V_{GND}	GND pin input voltage	V_{SS} (Note 3)	V_{AA} (Note 3)	
V_{IN-}	Inverting input voltage	$V_{GND} - 0.5$	$V_{GND} + 0.5$	
V_{CSD}	CSD pin input voltage	V_{SS}	V_{AA}	
V_{COMP}	COMP pin input voltage	V_{SS}	V_{AA}	
C_{COMP}	COMP pin phase compensation capacitor to GND	1	-	nF
V_{DT}	DT pin input voltage	0	V_{CC}	V
I_{OREF}	Reference output current to COM (Note 2)	0.3	0.8	mA
V_{OCSET}	OCSET pin input voltage	0.5	5	V
V_{CSH}	CSH pin input voltage	V_S	V_B	
dV_{SS}/dt	Allowable V_{SS} voltage slew rate upon power-up (Note4)	-	50	V/ms
I_{PW}	Input pulse width	10 (Note 5)	-	ns
f_{SW}	Switching Frequency	-	800	kHz
T_A	Ambient Temperature	-40	125	°C

Note 1: Logic operational for V_S equal to -5 V to $+200\text{ V}$. Logic state held for V_S equal to -5 V to $-V_{BS}$.

Note 2: Nominal voltage for V_{REF} is 5.1 V . I_{OREF} of $0.3 - 0.8\text{ mA}$ dictates total external resistor value on V_{REF} to be $6.3\text{ k}\Omega$ to $16.7\text{ k}\Omega$.

Note 3: GND input voltage is limited by I_{AAZ} and I_{SSZ} .

Note 4: V_{SS} ramps up from 0 V to 200 V .

Note 5: Output logic status may not respond correctly if input pulse width is smaller than the minimum pulse width.

Electrical Characteristics

Unless otherwise noted, these specifications apply for an operating junction temperature range of $-40^{\circ}\text{C} \leq T_j \leq 125^{\circ}\text{C}$ with bias conditions of $V_{CC}, V_{BS} = 12\text{ V}$, $V_{SS} = V_S = \text{COM} = 0\text{ V}$, $V_{AA} = 10\text{ V}$, $C_L = 1\text{ nF}$.

Symbol	Definition	Min	Typ	Max	Units	Test Conditions
Low Side Supply						
UV _{CC+}	V _{cc} supply UVLO positive threshold	8.4	8.9	9.8	V	
UV _{CC-}	V _{cc} supply UVLO negative threshold	8.2	8.7	9.4		
UV _{CCHYS}	UV _{CC} hysteresis	-	0.2	-		
I _{QCC}	Low side quiescent current	-	-	3	mA	V _{DT} =V _{CC}
V _{CLAMPL}	Low side zener diode clamp voltage	19.6	20.4	21.6	V	I _{CC} =5 mA
High Side Floating Supply						
UV _{BS+}	High side well UVLO positive threshold	8.0	8.5	9.7	V	
UV _{BS-}	High side well UVLO negative threshold	7.8	8.3	9.0		
UV _{BSHYS}	UV _{BS} hysteresis	-	0.2	-		
I _{QBS}	High side quiescent current	-	-	1	mA	
I _{LKH}	High to Low side leakage current	-	-	50	μA	V _B =V _S =200 V
V _{CLAMPH}	High side zener diode clamp voltage	19.6	20.4	21.6	V	I _{BS} =5 mA
Floating Input Supply						
UV _{AA+}	VA+, VA- floating supply UVLO positive threshold from V _{SS}	8.2	8.7	9.7	V	V _{SS} =0 V, GND pin floating
UV _{AA-}	VA+, VA- floating supply UVLO negative threshold from V _{SS}	7.7	8.2	9.0		V _{SS} =0 V, GND pin floating
UV _{AAHYS}	UV _{AA} hysteresis	-	0.5	-		V _{SS} =0 V, GND pin floating
I _{QAA0}	Floating Input positive quiescent supply current	-	0.5	2	mA	V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =V _{SS}
I _{QAA1}	Floating Input positive quiescent supply current	-	6.5	11		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =V _{AA} , T _j = -40C
		-	8	11		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =V _{AA} , T _j = 25C
		-	9.5	12.5		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =V _{AA} , T _j = 125C
I _{QAA2}	Floating Input positive quiescent supply current	-	6.5	11		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =GND, T _j = -40C
		-	8	11		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =GND, T _j = 25C
		-	9.5	12.5		V _{AA} =10 V, V _{SS} =0 V, V _{CSD} =GND, T _j = 125C
I _{LKM}	Floating input side to Low side leakage current	-	-	50	μA	V _{AA} =V _{SS} =V _{GND} = 100 V
V _{CLAMP+M}	V _{AA} floating supply zener diode clamp voltage, positive, with respect to GND	6.0	7.0	8.0	V	I _{AA} =5 mA, I _{SS} =5 mA, V _{GND} =0 V, V _{CSD} =V _{SS}
V _{CLAMP-M}	V _{SS} floating supply zener diode clamp voltage, negative, with respect to GND	-8.0	-7.0	-6.0		I _{AA} =5 mA, I _{SS} =5 mA, V _{GND} =0 V, V _{CSD} =V _{SS}
Audio Input (V _{GND} =0, V _{AA} =5V, V _{SS} =-5V)						
V _{OS}	Input offset voltage	-20	0	20	mV	T _j = -40C
		-15	0	15	mV	T _j = 25C
		-18	0	18	mV	T _j = 125C
I _{BIN}	Input bias current	-	-	40	nA	

BW	Small signal bandwidth	-	9	-	MHz	C _{COMP} =2 nF, R _f =3.3 kΩ
V _{COMP}	OTA Output voltage	VAA-1	-	VSS+1	V	
g _m	OTA transconductance	-	100	-	mS	V _{IN} =10 mV
G _V	OTA gain	60	-	-	dB	
V _{Nrms}	OTA input noise voltage	-	250	-	mVrms	BW=20 kHz, Resolution BW=22 Hz Fig.5
SR	Slew rate	-	±5	-	V/us	C _{COMP} =1 nF
CMRR	Common-mode rejection ratio	-	60	-	dB	
PSRR	Supply voltage rejection ratio	-	65	-		
PWM comparator						
V _{thP_{WM}}	PWM comparator threshold in COMP	-	(V _{AA} -V _{SS})/2	-	V	
f _{OTA}	COMP pin star-up local oscillation frequency	0.7	1.0	1.3	MHz	V _{CSD} =GND
Protection						
V _{REF}	Reference output voltage	4.8	5.1	5.5	V	I _{OREF} =0.5 mA
V _{thOCL}	Low side OC threshold in Vs	1.1	1.2	1.3		OCSET=1.2 V, Fig.6
V _{thOCH}	High side OC threshold in V _{CSH}	1.1+ Vs	1.2+ Vs	1.3+ Vs		Vs=200 V,
V _{th1}	CSD pin shutdown release threshold	0.62xV _{DD}	0.70xV _{DD}	0.78xV _{DD}		
V _{th2}	CSD pin self reset threshold	0.26xV _{DD}	0.30xV _{DD}	0.34xV _{DD}		
I _{CSD+}	CSD pin discharge current	60	100	150	μA	V _{CSD} = V _{SS} +5 V
I _{CSD-}	CSD pin charge current	60	100	150		V _{CSD} = V _{SS} +5 V
t _{SD}	Shutdown propagation delay from V _{CSD} > V _{SS} + V _{thOCH} to Shutdown	-	-	250	ns	
t _{OCH}	Propagation delay time from V _{CSH} > V _{thOCH} to Shutdown	-	-	650		Fig.3
t _{OCL}	Propagation delay time from Vs> V _{thOCL} to Shutdown	-	-	650		Fig.4
Gate Driver						
I _{o+}	Output high short circuit current (Source)	-	1.0	-	A	V _o =0 V, PW<10 μs
I _{o-}	Output low short circuit current (Sink)	-	1.2	-	A	V _o =12 V, PW<10 μs
V _{OL}	Low level out put voltage LO – COM, HO - VS	-	-	0.1	V	I _o =2 mA
V _{OH}	High level out put voltage VCC – LO, VB - HO	-	-	2.3		
t _{on}	High and low side turn-on propagation delay	-	360	-	ns	V _{DT} = V _{CC}
t _{off}	High and low side turn-off propagation delay	-	335	-		V _{DT} = V _{CC}
t _r	Turn-on rise time	-	20	50		
t _f	Turn-off fall time	-	15	35		
DT1	Deadtime: LO turn-off to HO turn-on (DT _{LO-HO}) & HO turn-off to LO turn-on (DT _{HO-LO})	5	20	35		V _{DT} >V _{DT1} , T _j = -40C
		15	25	35		V _{DT} >V _{DT1} , T _j = 25C
		20	35	50		V _{DT} >V _{DT1} , T _j = 125C
DT2	Deadtime: LO turn-off to HO turn-on (DT _{LO-HO}) & HO turn-off to LO turn-on (DT _{HO-LO})	20	35	55		V _{DT1} >V _{DT} > V _{DT2} , T _j = -40C
		25	40	55		V _{DT1} >V _{DT} > V _{DT2} , T _j = 25C
		30	50	70		V _{DT1} >V _{DT} > V _{DT2} , T _j = 125C
DT3	Deadtime: LO turn-off to HO turn-on (DT _{LO-HO}) & HO turn-off to LO turn-on (DT _{HO-LO})	40	65	95		V _{DT2} >V _{DT} > V _{DT3} , T _j = -40C
		50	65	85		V _{DT2} >V _{DT} > V _{DT3} , T _i = 25C

		50	80	105		$V_{DT2} > V_{DT} > V_{DT3}$, $T_j = 125C$
DT4	Deadtime: LO turn-off to HO turn-on (DT_{LO-HO}) & HO turn-off to LO turn-on (DT_{HO-LO}) $V_{DT} = V_{DT4}$	65	110	150		$V_{DT3} > V_{DT} > V_{DT4}$, $T_j = -40C$
		85	105	135		$V_{DT3} > V_{DT} > V_{DT4}$, $T_j = 25C$
		80	115	155		$V_{DT3} > V_{DT} > V_{DT4}$, $T_j = 125C$
V_{DT1}	DT mode select threshold 2	$0.51 \times V_{cc}$	$0.57 \times V_{cc}$	$0.63 \times V_{cc}$	V	
V_{DT2}	DT mode select threshold 3	$0.32 \times V_{cc}$	$0.36 \times V_{cc}$	$0.40 \times V_{cc}$		
V_{DT3}	DT mode select threshold 4	$0.21 \times V_{cc}$	$0.23 \times V_{cc}$	$0.25 \times V_{cc}$		

Waveform Definitions

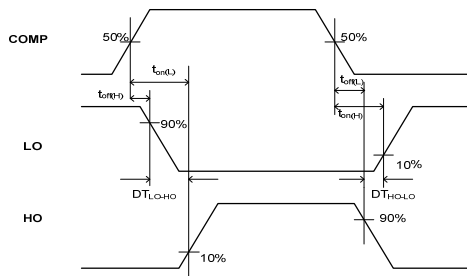


Figure 1: Switching Time Waveform Definitions

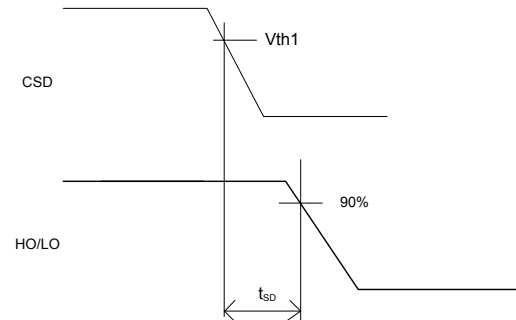


Figure 2: CSD to Shutdown Waveform Definitions

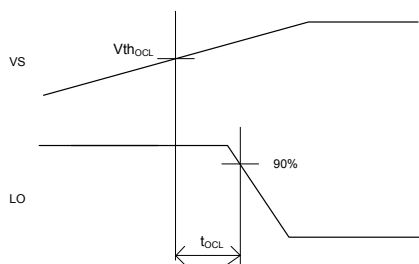


Figure 3: $V_S > V_{th_{OCL}}$ to Shutdown Waveform

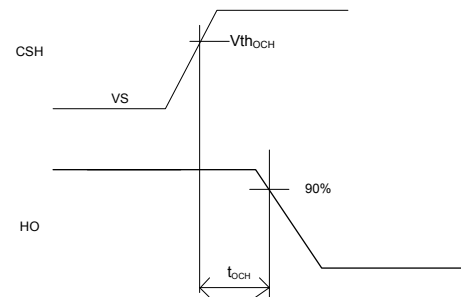


Figure 4: $V_{CSH} > V_{th_{OCH}}$ to Shutdown Waveform

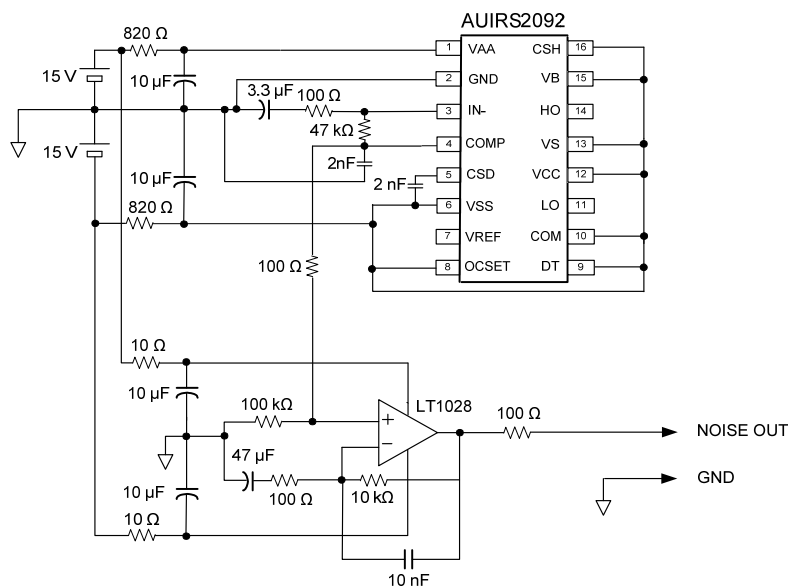
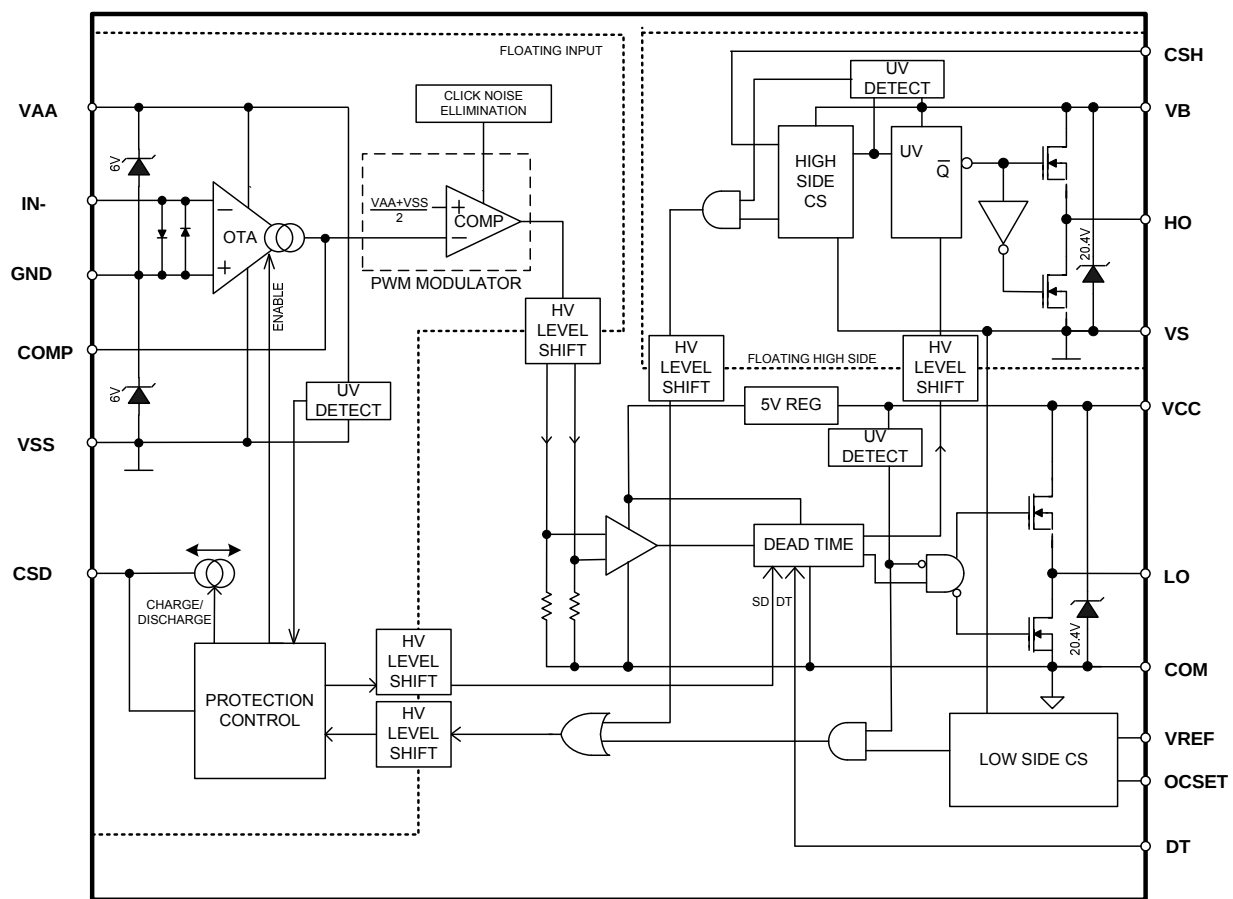
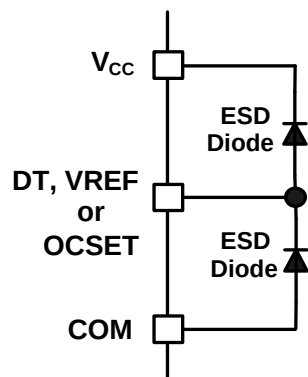
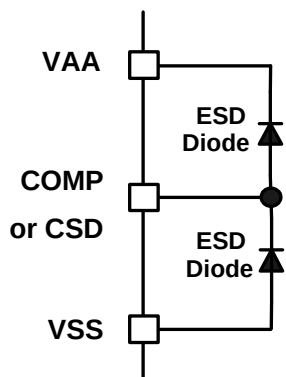
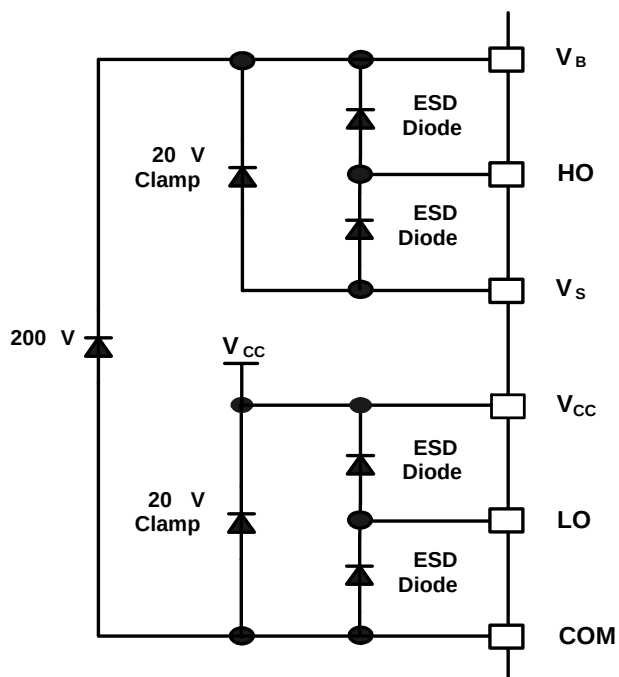
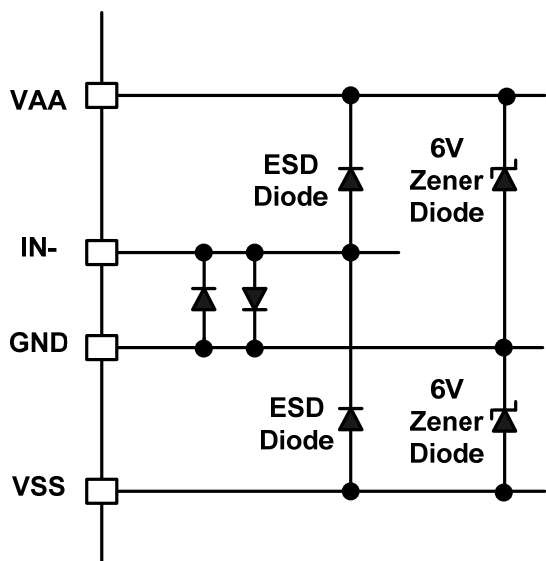


Figure 5: OTA input noise voltage measurement circuit

Functional Block Diagram: AUIRS2092



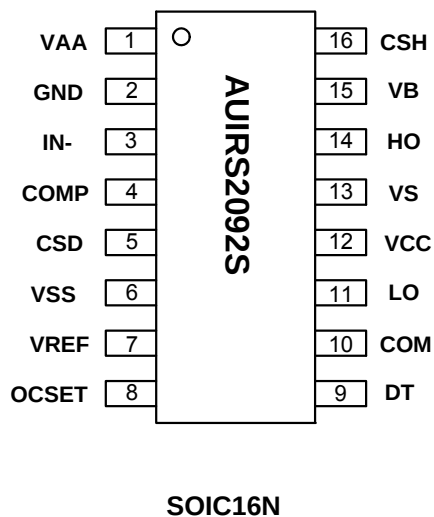
Input/Output Pin Equivalent Circuit Diagrams: AUIRS2092



Lead Definitions: AUIRS2092

Pin #	Symbol	Description
1	VAA	Floating input positive supply
2	GND	Floating input supply return
3	IN-	Analog inverting input
4	COMP	Phase compensation input, comparator input
5	CSD	Shutdown timing capacitor
6	VSS	Floating input negative supply
7	VREF	5V reference voltage to program OCSET pin
8	OCSET	Low side over current threshold setting
9	DT	Deadtime program input
10	COM	Low side supply return
11	LO	Low side output
12	VCC	Low side supply
13	VS	High side floating supply return
14	HO	High side output
15	VB	High side floating supply
16	CSH	High side over current sensing input

Lead Assignments



Parameter Temperature Trends

Figures illustrated in this chapter provide information on the experimental performance of the AUIRS2092S HVIC. The line plotted in each figure is generated from actual lab data. A large number of individual samples were tested at three temperatures (-40 °C, 25 °C, and 125 °C) in order to generate the experimental curve. The line consists of three data points (one data point at each of the tested temperatures) that have been connected together to illustrate the understood trend. The individual data points on the Typ. curve were determined by calculating the averaged experimental value of the parameter (for a given temperature).

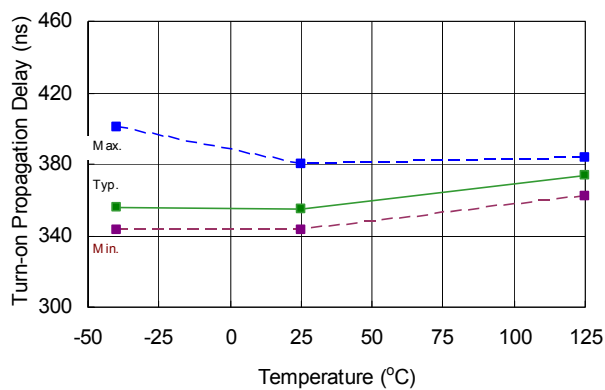


Figure 6: t_{ON} vs. temperature

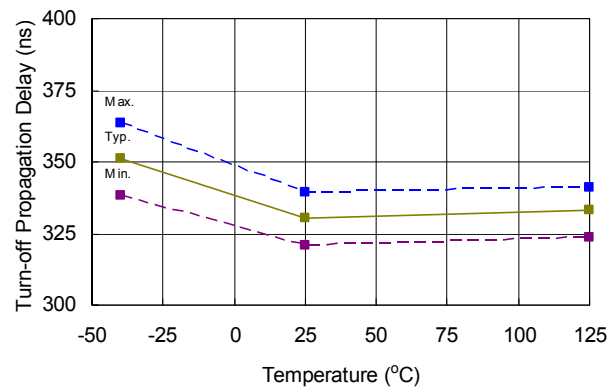


Figure 7: t_{OFF} vs. temperature

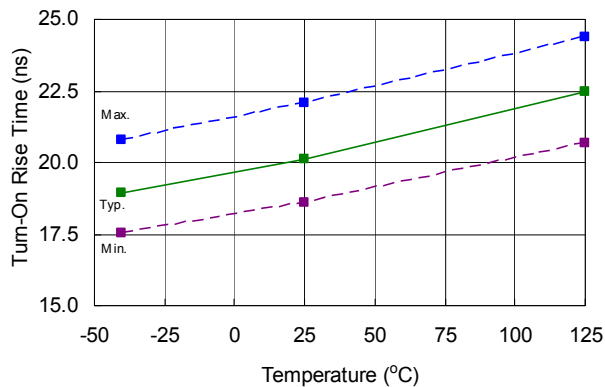


Figure 8: T_R vs. temperature

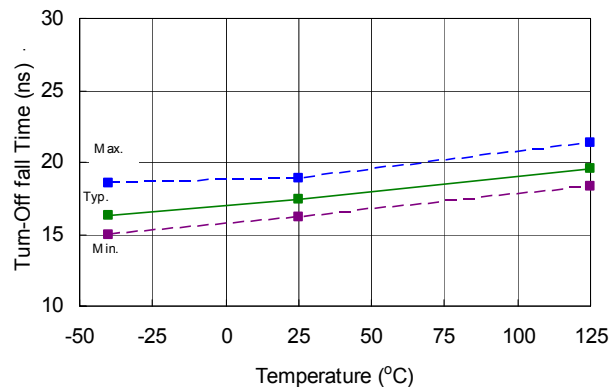


Figure 9: T_F vs. temperature

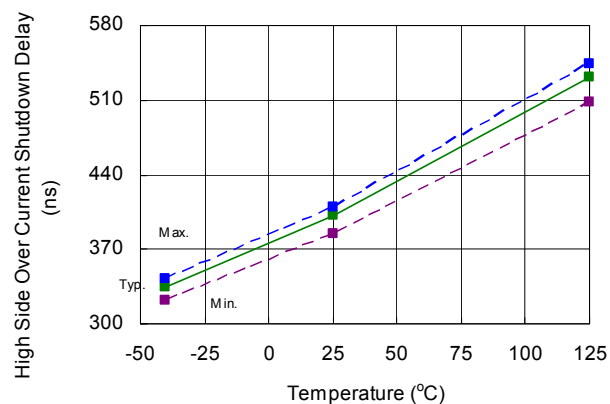


Figure 10: T_{OCH} vs. temperature

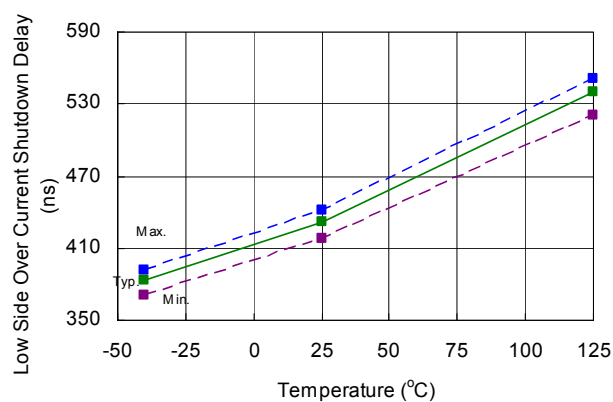


Figure 11: T_{OCL} vs. temperature

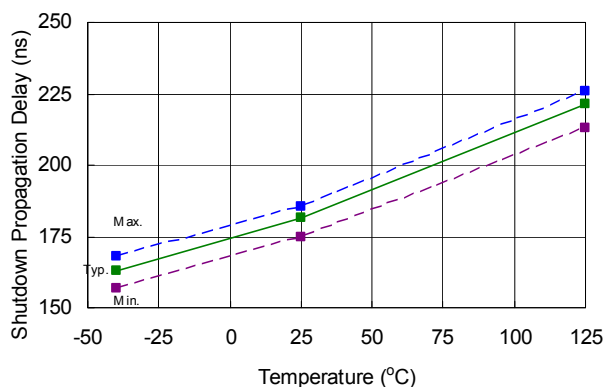


Figure 12: T_{SD} vs. temperature

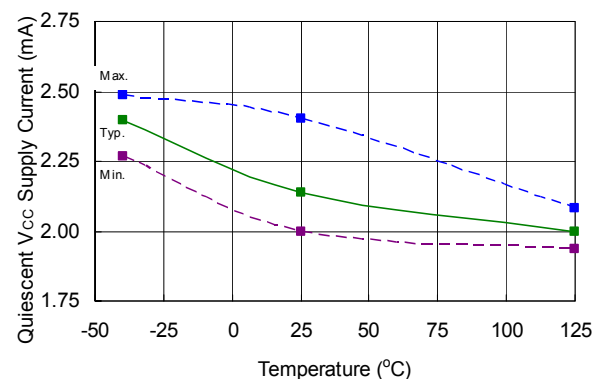


Figure 13: I_{QCC} vs. temperature

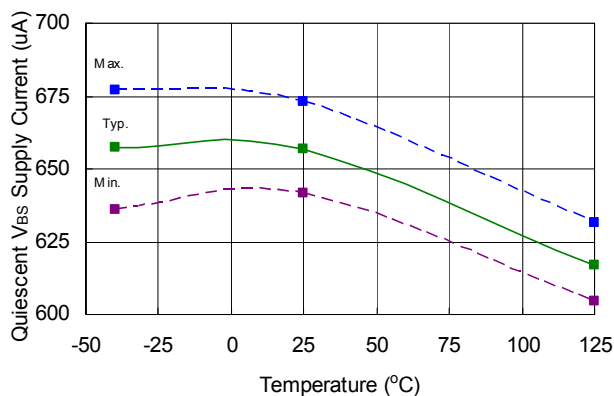


Figure 14: I_{QBS} vs. temperature

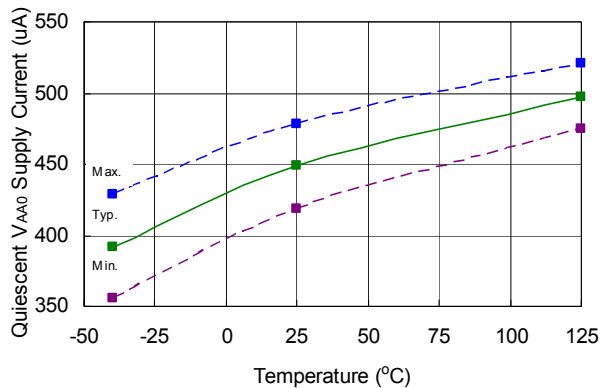


Figure 15: I_{QAA0} vs. temperature

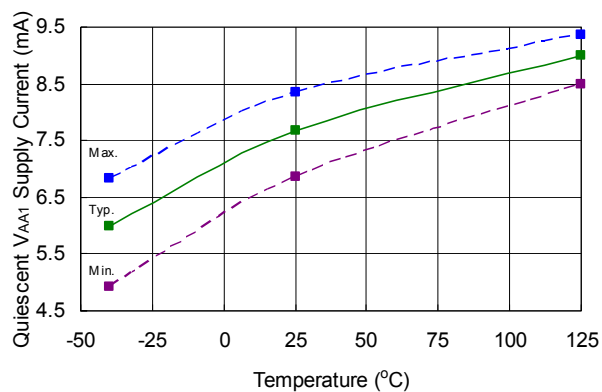


Figure 16: I_{QAA1} vs. temperature

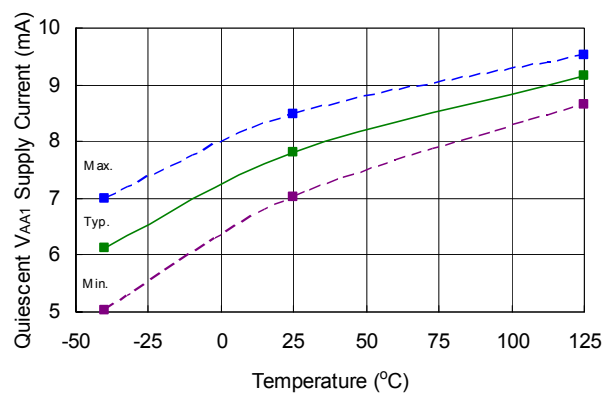


Figure 17: I_{QAA2} vs. temperature

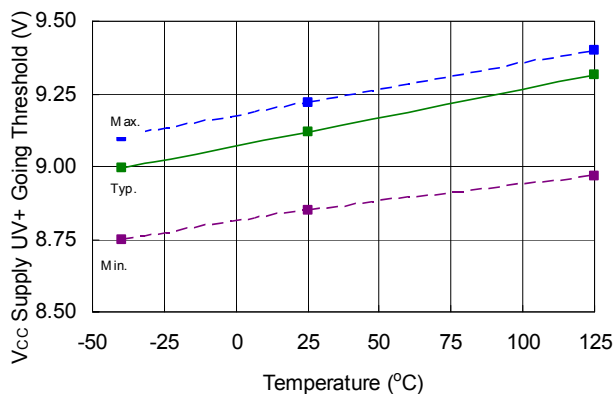


Figure 18: V_{CCUV+} vs. temperature

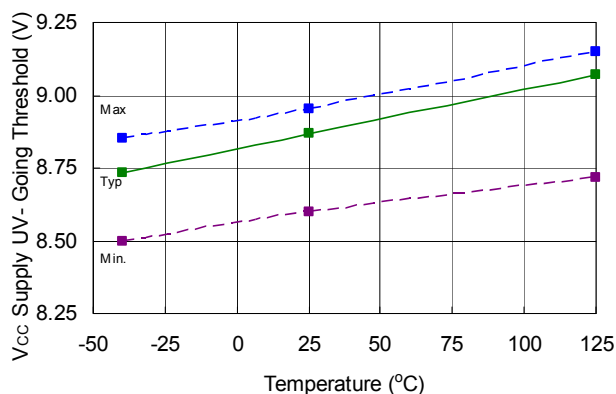


Figure 19: V_{CCUV-} vs. temperature

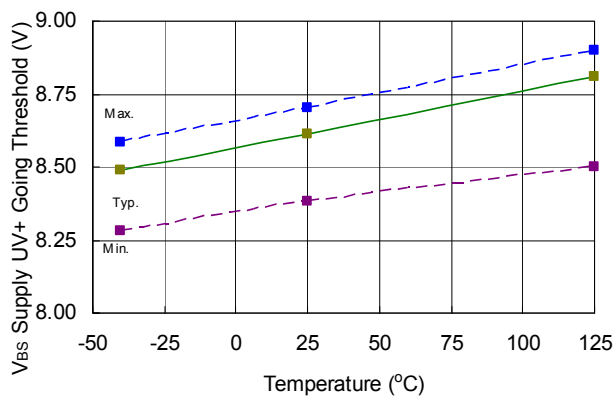


Figure 20: V_{BSUV+} vs. temperature

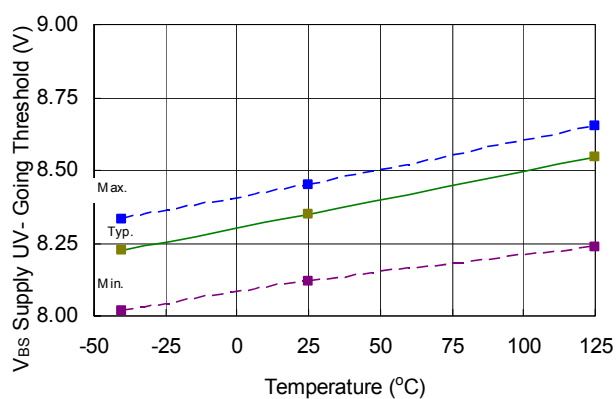


Figure 21: V_{BSUV-} vs. temperature

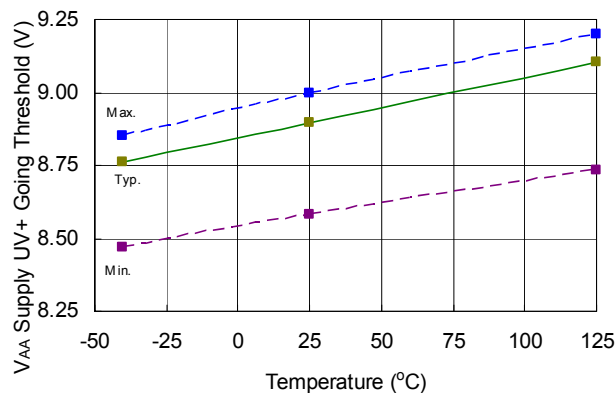


Figure 22: V_{AAUV+} vs. temperature

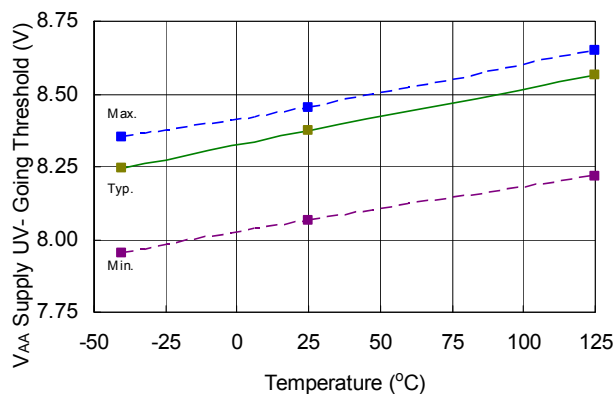


Figure 23: V_{AAUV-} vs. temperature

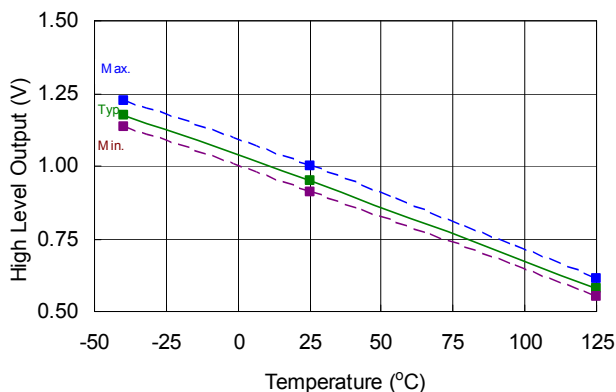


Figure 24: V_{OH} ($I_O = 0A$) vs. temperature

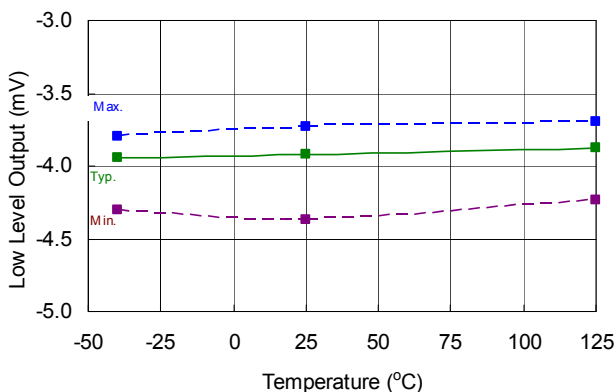


Figure 25: V_{OL} ($I_O = 0A$) vs. temperature

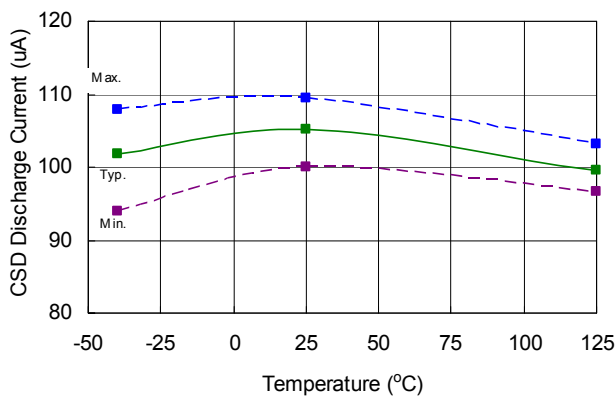


Figure 26: I_{CSD+} vs. temperature

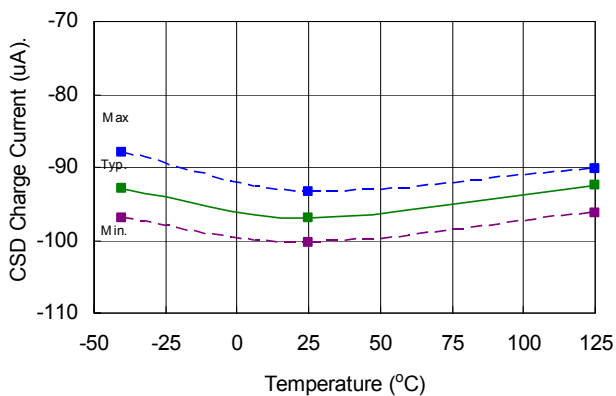


Figure 27: I_{CSD-} vs. temperature

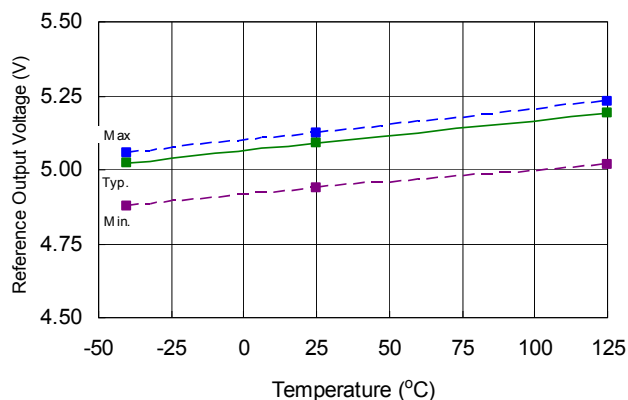
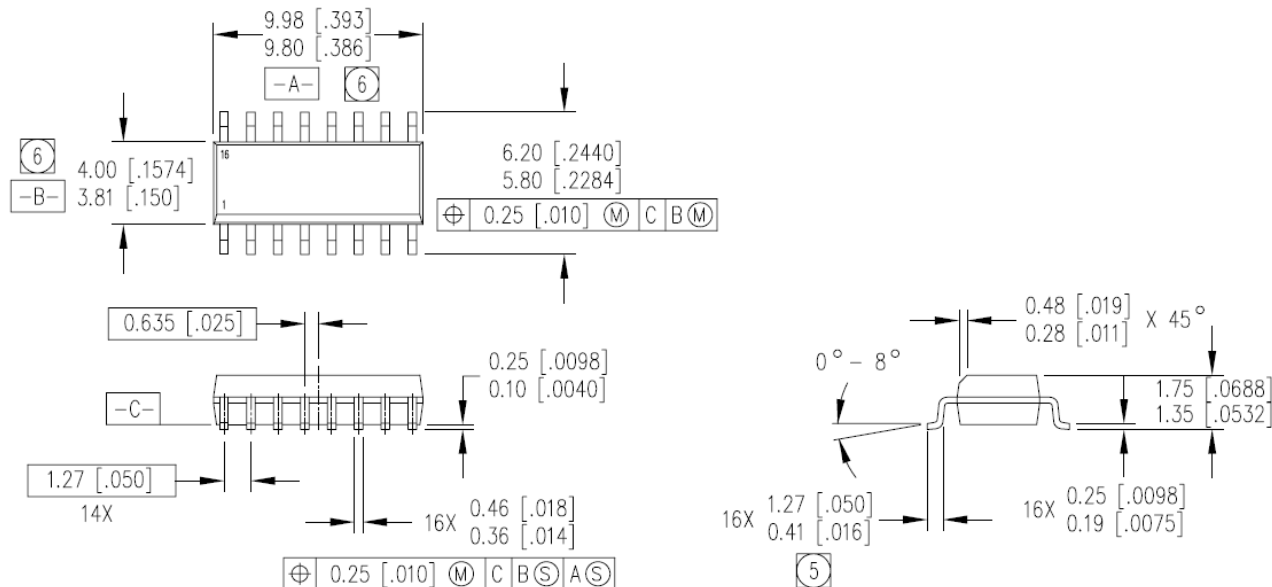


Figure 28: V_{REF} vs. temperature

Package Details: SOIC16N

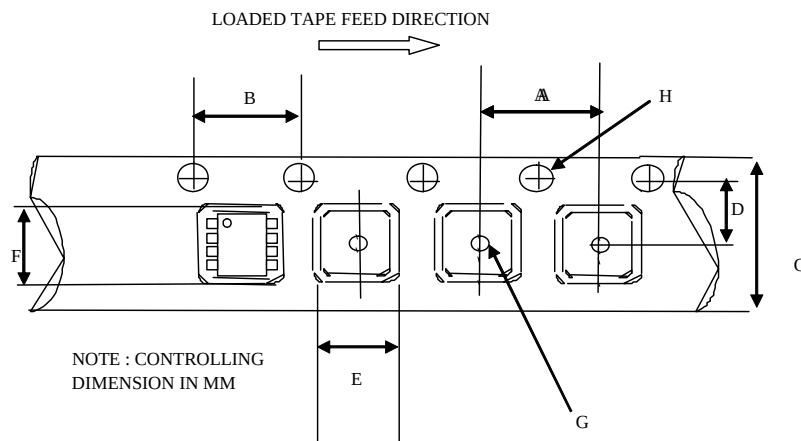


NOTES:

1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AC.

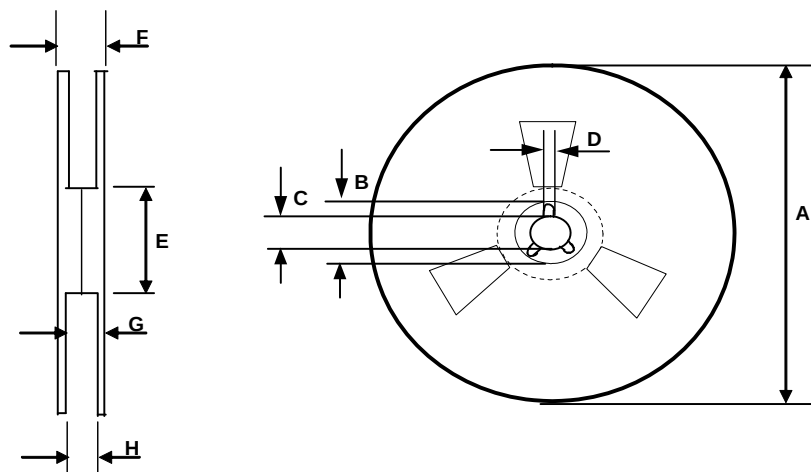
5. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.15 [.006].

Tape and Reel Details: SOIC16N



CARRIER TAPE DIMENSION FOR 16SOICN

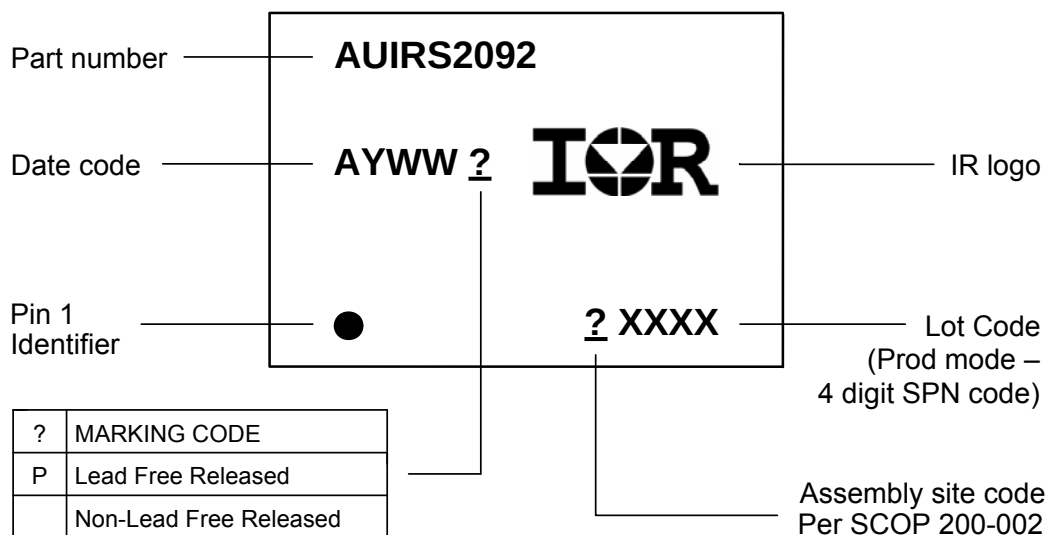
Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	15.70	16.30	0.618	0.641
D	7.40	7.60	0.291	0.299
E	6.40	6.60	0.252	0.260
F	10.20	10.40	0.402	0.409
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



REEL DIMENSIONS FOR 16SOICN

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	22.40	n/a	0.881
G	18.50	21.10	0.728	0.830
H	16.40	18.40	0.645	0.724

Part Marking Information



Ordering Information

Base Part Number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRS2092	SOIC16N	Tube/Bulk	45	AUIRS2092S
		Tape and Reel	2500	AUIRS2092STR

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<http://www.irf.com/technical-info/>

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Tel: (310) 252-7105

Revision History

Date	Comment
April 30, 2010	Converted from Industrial version
Aug. 5, 2010	Added tri-temp graphs;
Aug. 23, 2010	Updated Iqaa1,2,VOH,VOL,DT1,2,3,4, TOCH,TOCL,VOS, ICSD+/-, VREF, UVAA/CC/BS+/-; added Iqaa1-25,Iqaa2-25,DT1,2,3,4-25 parameters.
Sep. 1, 2010	Corrected DT1-25 max to 35. Added ESD and latchup classification
Jan. 19, 2011	Updated DT1-to-4, Vos, Iqaa1,2 tri-temp spec
Jan. 20, 2011	Added leadfree and automotive grade heading
Jan. 21, 2011	Added typical for IO on front page, merged DT,Vos, Iqaa repeated descriptions.
Mar. 11,2011	Changed notice address

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